National Semiconductor

June 1989

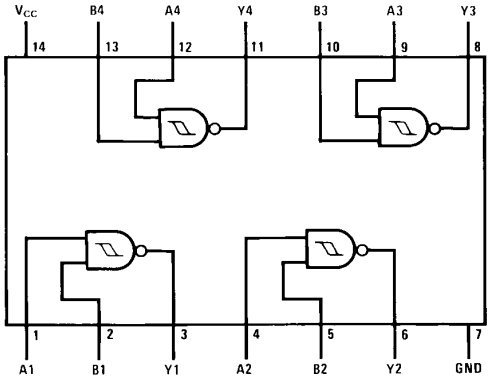
DM54LS132/DM74LS132 Quad 2-Input NAND Gates with Schmitt Trigger Inputs

General Description

This device contains four independent gates each of which performs the logic NAND function. Each input has hysteresis which increases the noise immunity and transforms a slowly changing input signal to a fast changing, jitter free output.

Connection Diagram

Dual-In-Line Package



TL/F/6389–1

Order Number DM54LS132J, DM54LS132W, DM74LS132M or DM74LS132N
See NS Package Number J14A, M14A, N14A or W14B

Function Table

$Y = \overline{AB}$

Inputs		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

H = High Logic Level

L = Low Logic Level

DM54LS132/DM74LS132 Quad 2-Input NAND Gates with Schmitt Trigger Inputs

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS	−55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	−65°C to +150°C

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter	DM54LS132			DM74LS132			Units
		Min	Nom	Max	Min	Nom	Max	
V_{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V_{T+}	Positive-Going Input Threshold Voltage (Note 1)	1.4	1.6	1.9	1.4	1.6	1.9	V
V_{T-}	Negative-Going Input Threshold Voltage (Note 1)	0.5	0.8	1	0.5	0.8	1	V
HYS	Input Hysteresis (Note 1)	0.4	0.8		0.4	0.8		V
I_{OH}	High Level Output Current			−0.4			−0.4	mA
I_{OL}	Low Level Output Current			4			8	mA
T_A	Free Air Operating Temperature	−55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 2)	Max	Units
V_I	Input Clamp Voltage	V_{CC} = Min, I_I = −18 mA				−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, I_{OH} = Max, V_I = V_{T-} Min	DM54	2.5	3.4		V
			DM74	2.7	3.4		
V_{OL}	Low Level Output Voltage	V_{CC} = Min, I_{OL} = Max, V_I = V_{T+} Max	DM54		0.25	0.4	V
			DM74		0.35	0.5	
		I_{OL} = 4 mA, V_{CC} = Min	DM74		0.25	0.4	
I_{T+}	Input Current at Positive-Going Threshold	V_{CC} = 5V, V_I = V_{T+}			−0.14		mA
I_{T-}	Input Current at Negative-Going Threshold	V_{CC} = 5V, V_I = V_{T-}			−0.18		mA
I_I	Input Current @ Max Input Voltage	V_{CC} = Max, V_I = 7V				0.1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.7V				20	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−0.4	mA
I_{OS}	Short Circuit Output Current	V_{CC} = Max (Note 3)	DM54	−20		−100	mA
			DM74	−20		−100	
I_{CCH}	Supply Current with Outputs High	V_{CC} = Max			5.9	11	mA
I_{CCL}	Supply Current with Outputs Low	V_{CC} = Max			8.2	14	mA

Note 1: V_{CC} = 5V

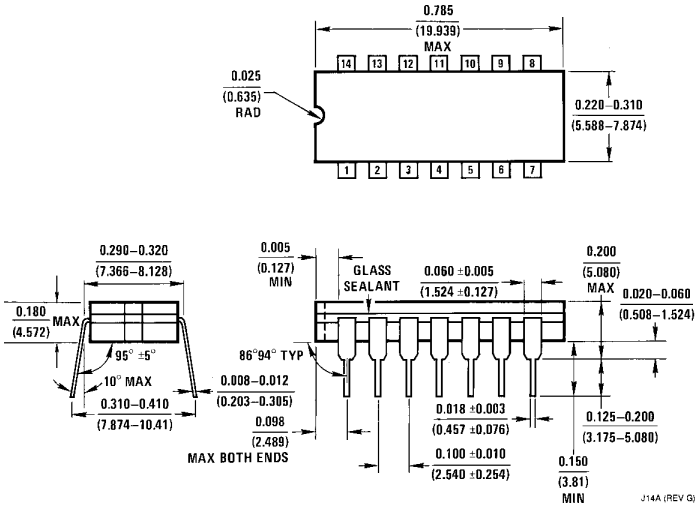
Note 2: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

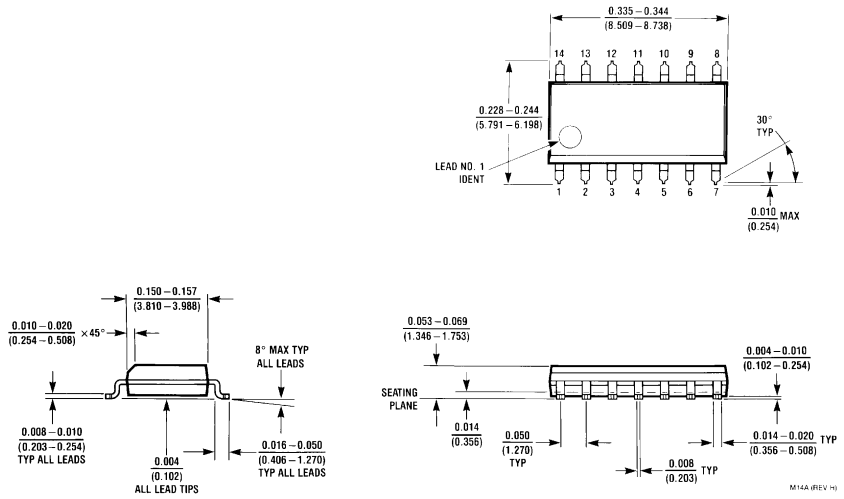
Switching Characteristics at V_{CC} 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	R_L = 2 kΩ				Units
		C_L = 15 pF		C_L = 50 pF		
		Min	Max	Min	Max	
t_{PLH}	Propagation Delay Time Low to High Level Output	5	22	8	25	ns
t_{PHL}	Propagation Delay Time High to Low Level Output	5	22	10	33	ns

Physical Dimensions inches (millimeters)

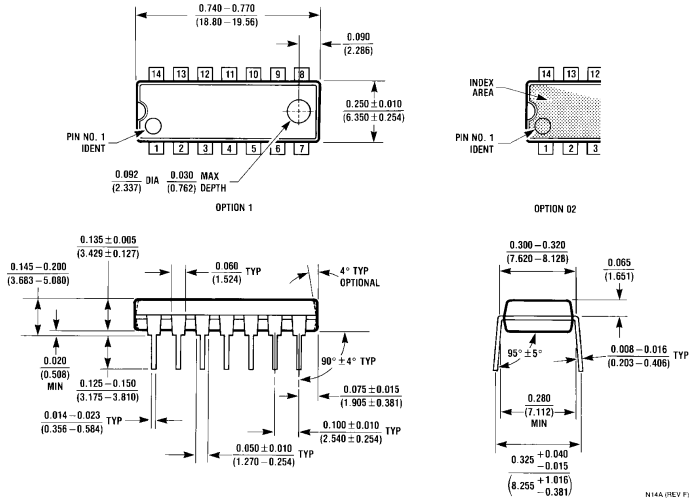


14-Lead Ceramic Dual-In-Line Package (J)
Order Number DM54LS132J
NS Package Number J14A

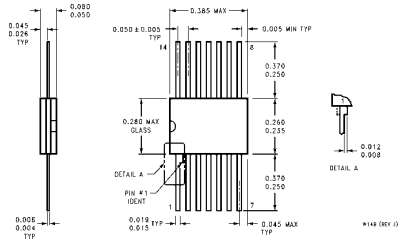


14-Lead Small Outline Molded Package (M)
Order Number DM74LS132M
NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Molded Dual-In-Line Package (N)
Order Number DM74LS132N
NS Package Number N14A



14-Lead Ceramic Flat Package (W)
Order Number DM54LS132W
NS Package Number W14B

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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